NSN 5961-01-543-4534

Transistor - Page 1 of 1

Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-543-4534 **Inclosure Material:** Metal **Overall Length:** 3.620 inches **Overall Height:** 1.125 inches **Overall Width:** 1.125 inches **End Application:** Fa-18 **Mounting Facility Quantity: Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 60.0 drain to source voltage and 60.0 drain to gate voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 150.00 amperes source cutoff current of standard range and 150.00 amperes zero-gate-voltage source current any acceptable **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Product Name:** Power transistor module, isolated base -- field effect, mos, n-channel, silicon **Terminal Type And Quantity:** 3 screw Shelf Life: N/a **Unit Of Measure: Demilitarization:** No